

O I P E

AUG 19 2005

First Named Inventor	Kirk D. Prall
Serial No.	10/786,765
Filing Date	February 25, 2004
Group Art Unit	2848 2814
Examiner Name	Unknown HOAI PHAM
Confirmation No.	2857
Attorney Docket No.	400.266US01
Title:	MULTI-LAYER MEMORY ARRAYS

**SECOND SUPPLEMENTAL
INFORMATION DISCLOSURE
STATEMENT
FORM PTO-1449**

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U.S. Patent References				
Examiner Initials	Document No.	Issue/Publication Date	Name	Filing Date
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Examiner Initials	Author, Title, Date, Pages, etc.

Examiner Signature	<i>Hoai Pham</i>	Date Considered	01/05/06
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*Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Based on Form PTO-FB-A820 Patent and Trademark Office, U.S. Department of Commerce

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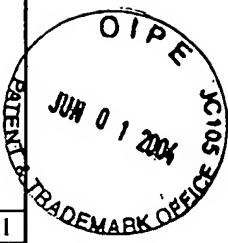
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